

# isc N-Channel MOSFET Transistor

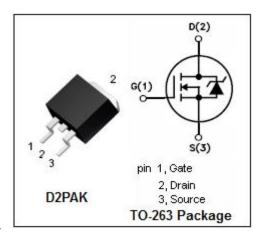
5N80

#### DESCRIPTION

- Drain Current I<sub>D</sub>= 5.5A@ T<sub>C</sub>=25°C
- Drain Source Voltage
  - : V<sub>DSS</sub>= 800V(Min)
- · Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

• Designed for high current, high speed switching, switch mode power supplies (SMPS), consumer and industrial lighting, DC-AC inverters for welding equipment and uninterruptible power supply(UPS)

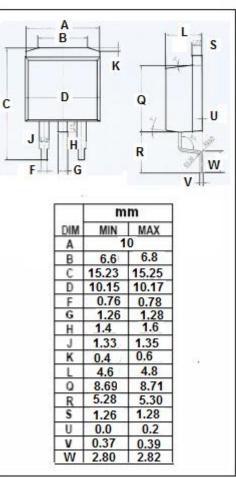


# ABSOLUTE MAXIMUM RATINGS(T<sub>C</sub>=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage (V <sub>GS</sub> =0)	800	V
$V_{GS}$	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-continuous@ T <sub>c</sub> =25℃	5.5	А
$I_{D(puls)}$	Pulse Drain Current	20	А
P <sub>tot</sub>	Total Dissipation@Tc=25℃	125	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}\mathbb{C}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	ction to Case 1	
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	Junction to Ambient 62.5	



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# • ELECTRICAL CHARACTERISTICS (T<sub>C</sub>=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 250μA	800			>
$V_{\text{GS}(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250μA	2.0		4.0	<b>V</b>
V <sub>SD</sub>	Diode Forward On-Voltage	I <sub>S</sub> =5.5A;V <sub>GS</sub> = 0			1.5	٧
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =2.5A			2.6	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0			250	μΑ

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